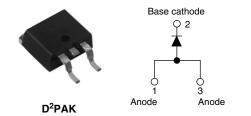


Vishay High Power Products

Input Rectifier Diode, 20 A



PRODUCT SUMMARY					
V _F at 10 A	1 V				
I _{FSM}	300 A				
V _{RRM}	800/1200 V				

DESCRIPTION/FEATURES

The 20ETS...S rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product series has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	16.3	21	А			

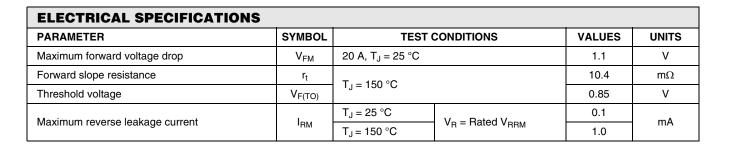
MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	20	A			
V _{RRM}		800/1200	V			
I _{FSM}		300	A			
V _F	20 A, T _J = 25 °C	1.1	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
20ETS08S	800	900	1				
20ETS12S	1200	1300	1				

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T_C = 105 °C, 180° conduction half sine wave	20		
Maximum peak one cycle		10 ms sine pulse, rated V_{RRM} applied	250	А	
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	316	A ² s	
	1-1	10 ms sine pulse, no voltage reapplied 442		A-5	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	4420	A²√s	

20ETS...S High Voltage Series

Vishay High Power Products Input Rectifier Diode, 20 A



THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature	e range	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.3	°C/W	
Maximum thermal resistance, junction to ambient		R _{thJA} ⁽¹⁾	For D ² PAK version	62		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5		
Approximate weight				2	g	
				0.07	oz.	
Mounting torque minimum maximum				6.0 (5.0)	kgf ⋅ cm	
					(lbf ⋅ in)	
Marking device			Case style D ² DAK (CMD 220)	20ET	S08S	
			Case style D ² PAK (SMD-220)	20ET	20ETS12S	

Note

(1) When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W

For recommended footprint and soldering techniques refer to application note #AN-994





20ETS...S High Voltage Series

Input Rectifier Diode, 20 A Vishay High Power Products

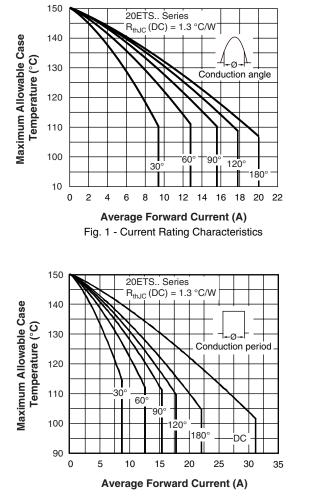
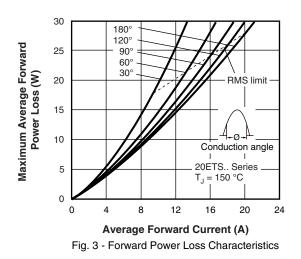


Fig. 2 - Current Rating Characteristics



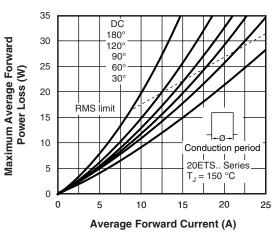
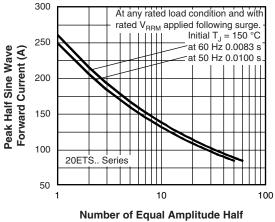
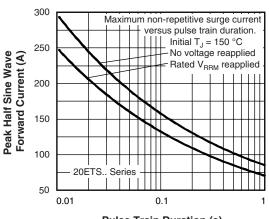
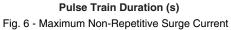


Fig. 4 - Forward Power Loss Characteristics



Cycle Current Pulse (N) Fig. 5 - Maximum Non-Repetitive Surge Current





20ETS...S High Voltage Series

Vishay High Power Products Input Rectifier Diode, 20 A



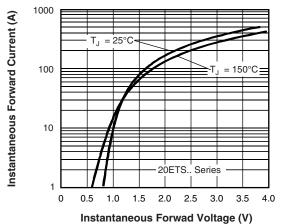


Fig. 7 - Forward Voltage Drop Characteristics

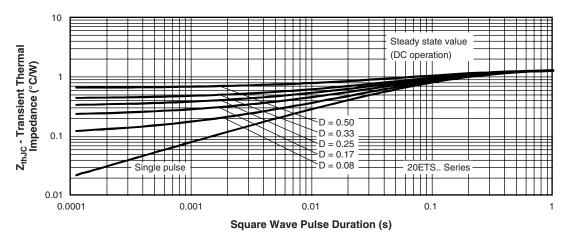


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Input Rectifier Diode, 20 A Vishay High Power Products

ORDERING INFORMATION TABLE

Device code	20	E	т	S	12	S	TRL	-	
		2	3	4	5	6	7	8	
	1 - 2 -	Circ	uit confi	ng (20 = guratior	-				
	3 -	Pac	E = Single diode Package: T = TO-220AC						
	4 -		e of silic Standar	on: d recove	ery recti	fier			
	5 - 6 -		-	le x 100 D ² PAK			sion	08 = 8 12 = 12	
	7 -		one = Tu RL = Tap	ube be and r	eel (left	oriente	d)		
	8 -	• TF • No	RR = Ta one = St	pe and r andard ad (Pb)-f	eel (righ producti	nt orient			

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95046					
Part marking information	http://www.vishay.com/doc?95054				
Packaging information	http://www.vishay.com/doc?95032				



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.